

Medium power transistor (−60V, −0.5A)

2SA2088

●Features

- 1) High speed switching. (Tf : Typ. : 60ns at Ic = −500mA)
- 2) Low saturation voltage, typically
(Typ. : −150mV at Ic = −100mA, Ib = −10mA)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SC5876

●Applications

Small signal low frequency amplifier
High speed switching

●Structure

PNP Silicon epitaxial planar transistor

●Packaging specifications

Type	Package	Taping
	Code	T106
	Basic ordering unit (pieces)	3000
2SA2088		○

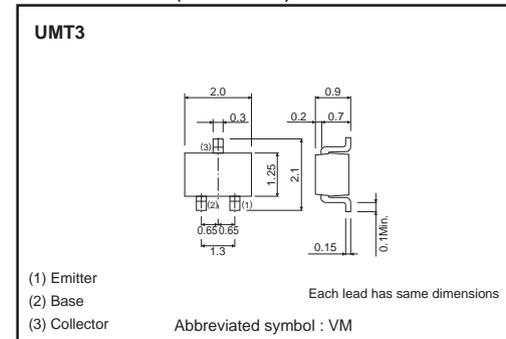
●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	−60	V
Collector-emitter voltage	V _{CE0}	−60	V
Emitter-base voltage	V _{EB0}	−6	V
Collector current	DC	I _c	−0.5 A
	Pulsed	I _{cP}	−1.0 A
Power dissipation	P _c	200	mW
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	−55 to 150	°C

*1 Pw=10ms

*2 Each terminal mounted on a recommended land

●Dimensions (Unit : mm)



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector-emitter breakdown voltage	BV_{CEO}	-60	-	-	V	$I_C = -1mA$
Collector-base breakdown voltage	BV_{CBO}	-60	-	-	V	$I_C = -100\mu A$
Emitter-base breakdown voltage	BV_{EBO}	-6	-	-	V	$I_E = -100\mu A$
Collector cut-off current	I_{CBO}	-	-	-1.0	μA	$V_{CB} = -40V$
Emitter cut-off current	I_{EBO}	-	-	-1.0	μA	$V_{EB} = -4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	-150	-500	mV	$I_C = -100mA$ $I_B = -10mA$
DC current gain	h_{FE}	120	-	270	-	$V_{CE} = -2V$ $I_C = -50mA$
Transition frequency	f_T	-	400	-	MHz	$V_{CE} = -10V$ $I_E = 100mA$ $f = 10MHz$
Corrector output capacitance	C_{ob}	-	10	-	pF	$V_{CB} = -10V$ $I_E = 0A$ $f = 1MHz$
Turn-on time	t_{on}	-	35	-	ns	$I_C = -500mA$ $I_{B1} = -50mA$ $I_{B2} = -50mA$ $V_{CC} = -25V$
Storage time	t_{stg}	-	100	-	ns	
Fall time	t_f	-	60	-	ns	

*1 Non repetitive pulse

*2 See Switching characteristics measurement circuits

●hFE RANK

Q
120-270

●Electrical characteristic curves

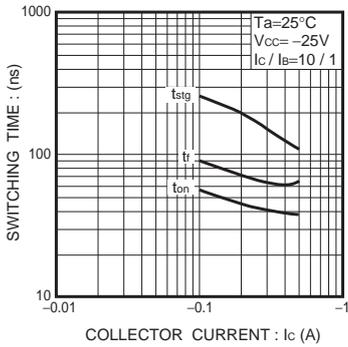


Fig.1 Switching Time

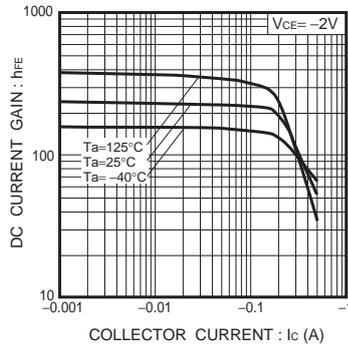


Fig.2 DC Current Gain vs. Collector Current (I)

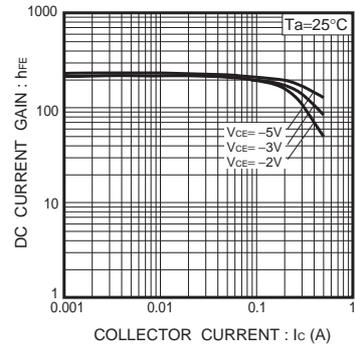


Fig.3 DC Current Gain vs. Collector Current (II)

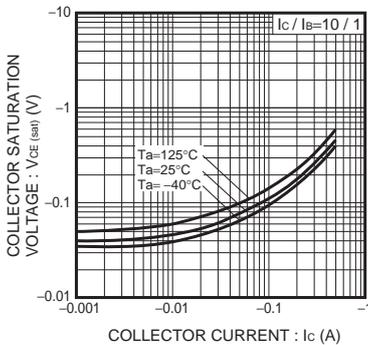


Fig.4 Collector-Emitter Saturation Voltage vs. Collector Current (I)

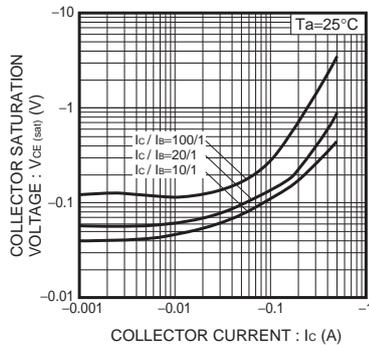


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II)

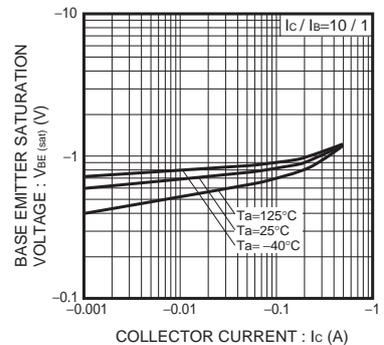


Fig.6 Base-Emitter Saturation Voltage vs. Collector Current

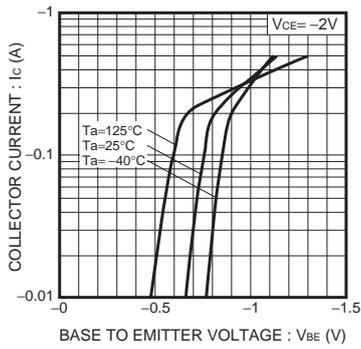


Fig.7 Grounded Emitter Propagation Characteristics

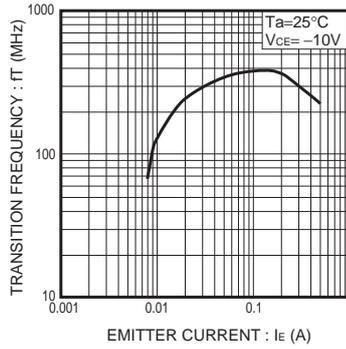


Fig.8 Transition Frequency

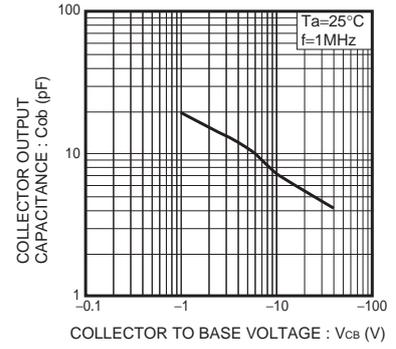
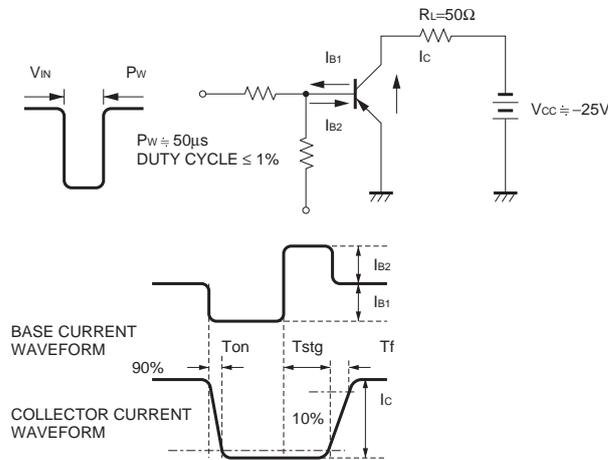


Fig.9 Collector Output Capacitance

●Switching characteristics measurement circuits



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